



# Fault-Protected Single 8-Ch/Differential 4-Ch Analog Multiplexers

#### **DESCRIPTION**

The DG458 and DG459 are 8-channel single-ended and 4-channel differential analog multiplexers, respectively, incorporating fault protection. A series n-p-n MOSFET structure provides device and signal-source protection in the event of power loss or overvoltages. Under fault conditions the multiplexer input (or output) appears as an open circuit and only a few nanoamperes of leakage current will flow. This protects not only the multiplexer and the circuitry following it, but also protects the sensors or signal sources which drive the multiplexer.

The DG458 and DG459 can withstand continuous overvoltage inputs up to ± 35 V. All digital inputs have TTL compatible logic thresholds. Break-before-make operation prevents channel-to-channel interference.

The DG458 and DG459 are improved pin-compatible replacements HI-508A/509A MAX358/359 multiplexers.

#### **FEATURES**

- Fault and Overvoltage Protection
- All Channels Off When Power Off
- Latchup-Proof
- Fast Switching t<sub>A</sub>: 200 ns
- Break-Before-Make Switching
- Low On-Resistance: 180 W
- Low Power Consumption: 3 mW
- TTL and CMOS Compatible Inputs

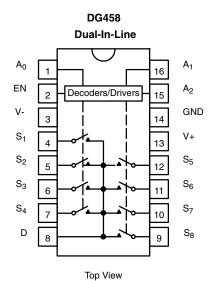
#### **BENEFITS**

- · Improved Ruggedness
- Power Loss Protection
- Prevents Adjacent Channel Crosstalk
- Standard Logic Interface
- Superior Accuracy
- · Fast Settling Time

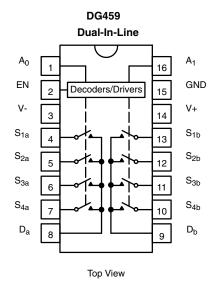
#### **APPLICATIONS**

- · Data Acquisition Systems
- Industrial Process Control Systems
- Avionics Test Equipment
- High-Rel Control Systems
- Telemetry

#### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



<sup>\*</sup> Pb containing terminations are not RoHS compliant, exemptions may apply







#### THRU TABLES AND ORDERING INFORMATION

TRUT	TRUTH TABLE - DG458								
A <sub>2</sub>	A <sub>1</sub>	A <sub>0</sub>	EN	On Switch					
Х	Х	Х	0	None					
0	0	0	1	1					
0	0	1	1	2					
0	1	0	1	3					
0	1	1	1	4					
1	0	0	1	5					
1	0	1	1	6					
1	1	0	1	7					
1	1	1	1	8					

TRUTH	TRUTH TABLE - DG459							
A <sub>1</sub>	A <sub>0</sub>	EN	On Switch					
Х	Х	0	None					
0	0	1	1					
0	1	1	2					
1	0	1	3					
1	1	1	4					

Logic "0" =  $V_{AL} \le 0.8 \text{ V}$ Logic "1" =  $V_{AH} \ge 2.4 \text{ V}$ X = Don't Care

ORDERING INFORMATION						
Temp Range	Package	Part Number				
- 40 to 85 °C	16 pin Plactic DIP	DG458DJ DG458DJ-E3				
- 40 to 65 C	16-pin Plastic DIP	DG459DJ DG459DJ-E3				

ABSOLUTE MAXIMUM RATINGS					
Parameter		Limit	Unit		
V+ to V-		44			
V+ to GND		22			
V- to GND		- 25			
V <sub>EN</sub> , V <sub>A</sub> Digital Input		(V-) - 4 to (V+) + 4	V		
V <sub>S</sub> , Analog Input Overvoltage with	n Power On	(V-) - 20 to (V+) + 20			
V <sub>S</sub> , Analog Input Overvoltage with	Power Off	- 35 to + 35			
Continuous Current, S or D		20	A		
Peak Current, S or D (Pulsed at 1	ms, 10 % duty cycle max)	40	mA		
Storage Tomporature	(AK Suffix)	- 65 to 150	°C		
Storage Temperature (DJ Suffix)		- 65 to 125			
	16-pin Plastic DIP <sup>B</sup>	600			
Power Dissipation (Package) <sup>a</sup>	16-pin CerDIP <sup>C</sup>	1000	mW		
	LCC-20 <sup>d</sup>	1000			

#### Notes:

- a. All leads soldered or welded to PC board.
- b. Derate 6.3 mW/°C above 75 °C.
- c. Derate 12 mW/°C above 75 °C.
- d. Derate 10 mW/°C above 75 °C.



SPECIFICATIONS <sup>a</sup>		Test Condition				_ A A	uffix	D 0	uffix	1
		Unless Otherwise S					<b>итих</b> о 125°C			
		V+ = 15 V, V- = -								
Parameter	Symbol	$V_{AL} = 0.8 \text{ V}, V_{AH} =$	2.4 V <sup>f</sup>	Temp.b	Typ. <sup>c</sup>	Min. <sup>d</sup>	Max.d	Min. <sup>d</sup>	Max.d	Unit
Analog Switch										
Analog Signal Range <sup>e</sup>	$V_{ANALOG}$			Full		- 10	10	- 10	10	V
Drain-Source On-Resistance	R <sub>DS(on)</sub>	$V_D = \pm 9.5 \text{ V}, I_S = -6$		Room Full	0.45		1.2 1.5		1.5 1.8	kΩ
On-i resistance		$V_D = \pm 5 \text{ V}, I_S = -4$	00 μΑ	Room	180		400		400	Ω
R <sub>DS(on)</sub> Matching Between Channels <sup>h</sup>	$\Delta R_{DS(on)}$	$V_D = 0 V, I_S = -40$	00 μΑ	Room	6					%
Source Off Leakage Current	I <sub>S(off)</sub>	$V_{EN} = 0 \text{ V}, V_{D} = \pm V_{S} = \pm 10 \text{ V}$	10 V	Room Full	0.03	- 0.5 - 50	0.5 50	- 1 - 20	1 20	
Drain Off Leakage Current	I <sub>D(off)</sub>	$V_{EN} = 0 \text{ V}$ $V_{D} = \pm 10 \text{ V}$	DG458	Room Full	0.1	- 1 - 200	1 200	- 1 - 50	1 50	
· ·	'D(οπ)	$V_{S} = \pm 10 \text{ V}$	DG459	Room Full	0.1	- 1 - 100	1 100	- 2 - 25	2 25	nA
Differential Off Drain Leakage Current	I <sub>DIFF</sub>	DG459 Only		Room		- 50	50	- 20	20	
Drain On Leakage Current	I <sub>D(on)</sub>	$V_{S} = V_{D} = \pm 10 \text{ V}$	DG458	Room Full	0.1	- 2 - 200	2 200	- 5 - 50	5 50	
Brain on Leakage Guirent	·D(on)	13 - 10 T	DG459	Room Full	0.05	- 2 - 100	2 100	- 5 - 25	5 25	
Fault										
Output Leakage Current (with Overvoltage)	$I_{D(off)}$	$V_S = \pm 33 \text{ V}, V_D = \text{See Figure 1}$		Room	0.02					nA
Input Leakage Current (with Overvoltage)		$V_S = \pm 25 \text{ V}, V_D =$ See Figure 1	10 V,	Room	0.005	- 5	5	- 10	10	4
Input Leakage Current (with Power Supplies Off)	I <sub>S(off)</sub>	$V_S = \pm 25 \text{ V}, V_{SUPS}$ $V_D = A_0, A_1, A_2, EN$	•	Room	0.001	- 2	2	- 5	5	μΑ
Digital Control				•		•	!			
Input Low Threshold	V <sub>AI</sub>			Full			0.8		0.8	V
Input Low Threshold	$V_{AL}$			Full		2.4		2.4		
Logic Input Control	I <sub>A</sub>	$V_A = 2.4 \text{ V or } 0.$	8 V	Full		- 1	1	- 1	1	μΑ



SPECIFICATIONS <sup>a</sup>										
		Test Conditions Unless Otherwise Sp V+ = 15 V, V- = -1	ecified			_	uffix o 125°C	_	uffix to 85 °C	
Parameter	Symbol	$V_{AL} = 0.8 \text{ V}, V_{AH} = 2$		Temp.b	Typ. <sup>c</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Min. <sup>d</sup>	Max. <sup>d</sup>	Unit
Dynamic Characteristics				ı	ı					
Transition Time	t <sub>A</sub>	See Figure 3		Room	200		500		500	
Break-Before-Make Interval	t <sub>OPEN</sub>	See Figure 4		Room	45	10		10		
Enable Turn-On Time	t <sub>ON(EN)</sub>	Coo Figure 5		Room Full	140		250 500		250 500	ns
Enable Turn-Off Time	t <sub>OFF(EN)</sub>	See Figure 5		Room Full	50		250 500		250 500	
O-Missa Tisas	+	To 0.1 %		Room	0.5					
Settling Time	t <sub>s</sub>	To 0.01 %	Room	1.5					μs	
Off Isolation	OIRR	$V_{EN} = 0 \text{ V, R}_{L} = 1$ $C_{L} = 15 \text{ pF, V}_{S} = 3 \text{ V}_{S}$ $f = 100 \text{ kHz}$		Room	90					dB
Logic Input Capacitance	C <sub>in</sub>	f = 1 MHz		Room	5					
Source Off Capacitance	C <sub>S(off)</sub>			Room	5					
Drain Off Canacitanas	6		DG458	Room	15					pF
Drain Off Capacitance	C <sub>D(off)</sub>		DG459	Room	10					рг
Drain On Capacitance	C		DG458	Room	40					Ì
Diairi On Capacitance	C <sub>D(on)</sub>		DG459	Room	35					†
Power Supplies										
Positive Supply Current	I+	V <sub>EN</sub> = 5 or 0 V, V <sub>A</sub> =	- 0 V	Room Full	0.05		0.1 0.2		0.1 0.2	mA
Negative Supply Current	I-	v <sub>EN</sub> = 5 01 0 v, v <sub>A</sub> = 0 v		Room Full	- 0.01	- 0.1 - 0.2		- 0.1 - 0.2		''''
Power Supply Range for Continuous Operation				Room		± 4.5	± 18	± 4.5	± 18	٧

#### Notes:

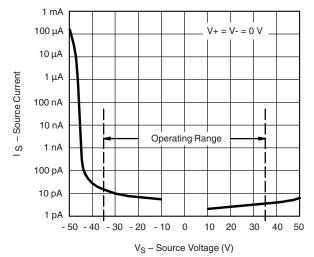
- a. Refer to PROCESS OPTION FLOWCHART.
- b. Room = 25 °C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.
- f.  $V_{IN}$  = input voltage to perform proper function.
- g. When the analog signal exceeds the + 13.5 V or 12 V,  $R_{DS(on)}$  starts to rise until only leakage currents flow.

h. 
$$\Delta R_{DS(on)} = \left(\frac{R_{DS(on)} MAX - R_{DS(on)} MIN}{Rr_{DS(on)} AVE}\right) x 100 \%$$

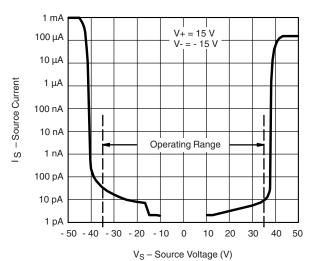
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



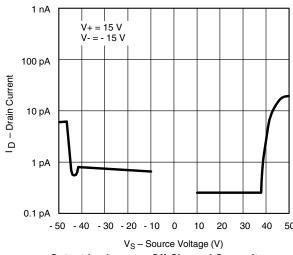
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



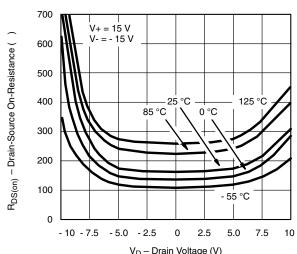
#### Input Leakage vs. Input Voltage



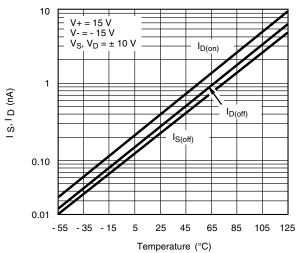
Off-Channel Leakage Currents vs. Input Voltage



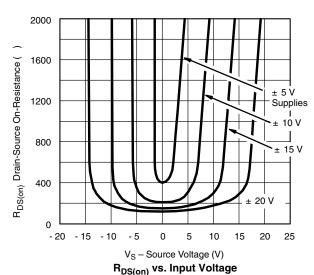
Output Leakage vs. Off-Channel Overvoltage



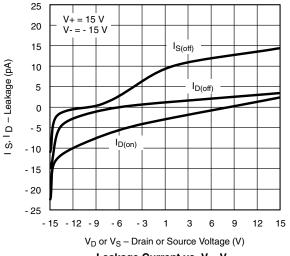
 $\begin{aligned} & V_D - \text{Drain Voltage (V)} \\ & \textbf{R}_{\text{DS(on)}} \ \text{vs.} \ \ V_D \ \text{and Temperature} \end{aligned}$ 



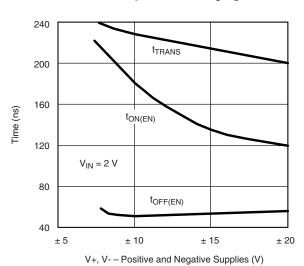
Leakage Currents vs. Temperature



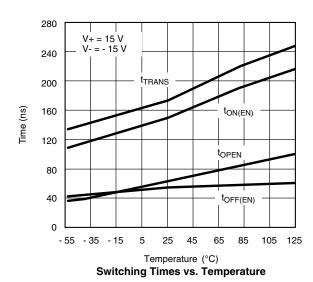
### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

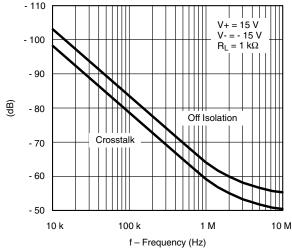


Leakage Current vs. V<sub>S</sub>, V<sub>D</sub>

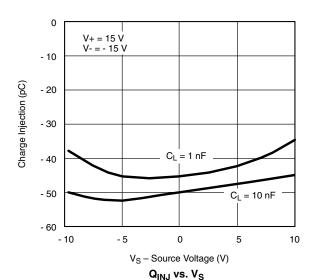


Switching Times ( $t_{TRANS}, t_{ON}, t_{OFF}$ ) vs.  $\pm$   $V_{SUPPLIES}$ 





Off Isolation and  $X_{TALK}$  vs. Frequency

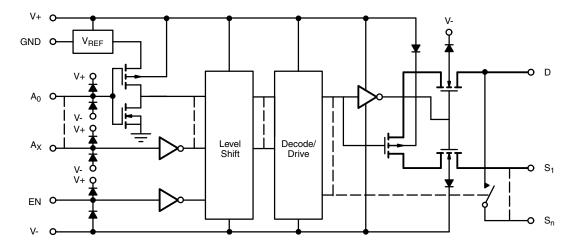


3.0 2.5 2.0 VTH (V) 1.5 1.0 0.5 0 20 2.5 5 7.5 10 12.5 15 17.5 V+, Supply (V)

Logic Input Switching Threshold vs. ± V<sub>SUPPLIES</sub>



#### **SCHEMATIC DIAGRAM (TYPICAL CHANNEL)**



#### **TEST CIRCUITS**

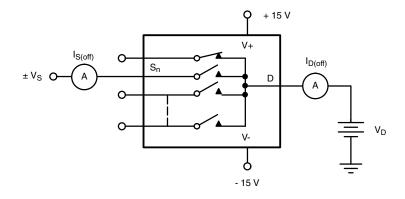


Figure 2. Analog Input Overvoltage

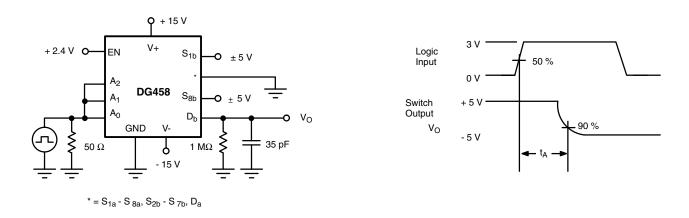
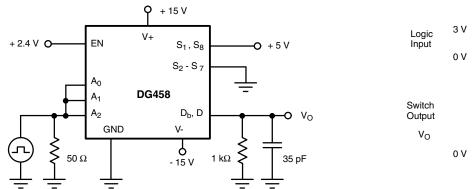


Figure 3. Transition Time

#### **TEST CIRCUITS**



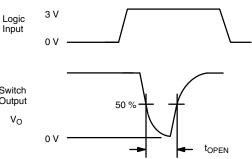
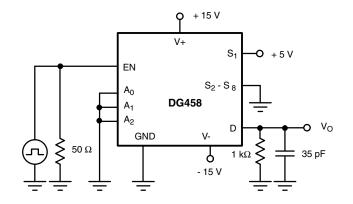


Figure 4. Break-Before-Make Time



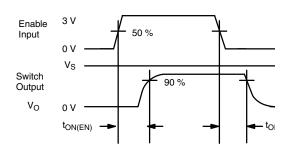


Figure 5. Enable Delay



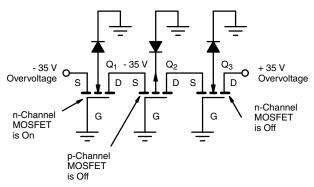


#### **DETAILED DESCRIPTION**

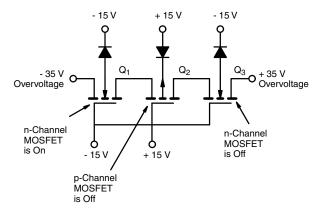
The Vishay Siliconix DG458 and DG459 multiplexers are fully fault- and overvoltage-protected for continuous input voltages up to  $\pm$  35 V whether or not voltage is applied to the power supply pins (V+, V-). These multiplexers are built on a high-voltage junction-isolated silicon-gate CMOS process. Two n-channel and one p-channel MOSFETs are connected in series to form each channel (Figure 1).

Within the normal analog signal range (± 10 V), the R<sub>DS(on)</sub> variation as a function of analog signal voltage is comparable to that of the classic parallel N-MOS and P-MOS switches.

When the analog signal approaches or exceeds either supply rail, even for an on-channel, one of the three series MOSFETs gets cut-off, providing inherent protection against overvoltages even if the multiplexer power supply voltages are lost. This protection is good up to the breakdown voltage of the respective series MOSFETs. Under fault conditions only sub microamp leakage currents can flow in or out of the multiplexer. This not only provides protection for the multiplexer and succeeding circuitry, but it allows normal, undisturbed operation of all other channels. Additionally, in case of power loss to the multiplexer, the loading caused on the transducers and signal sources is insignificant, therefore redundant multiplexers can be used on critical applications such as telemetry and avionics.



(a) Overvoltage with Multiplexer Power Off

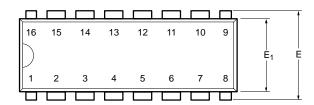


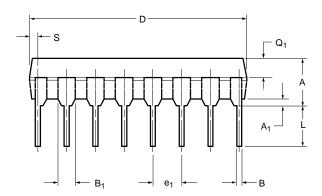
(b) Overvoltage with Multiplexer Power On Figure 5. Overvoltage Protection

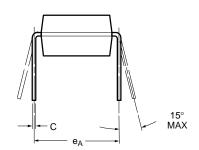
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?70064.



PDIP: 16-LEAD







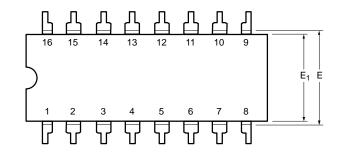
	MILLIN	IETERS	INC	HES			
Dim	Min	Max	Min	Max			
Α	3.81	5.08	0.150	0.200			
A <sub>1</sub>	0.38	1.27	0.015	0.050			
В	0.38	0.51	0.015	0.020			
B <sub>1</sub>	0.89	1.65	0.035	0.065			
С	0.20	0.30	0.008	0.012			
D	18.93	21.33	0.745	0.840			
E	7.62	8.26	0.300	0.325			
E <sub>1</sub>	5.59	7.11	0.220	0.280			
e <sub>1</sub>	2.29	2.79	0.090	0.110			
e <sub>A</sub>	7.37	7.87	0.290	0.310			
L	2.79	3.81	0.110	0.150			
Q <sub>1</sub>	1.27	2.03	0.050	0.080			
S	0.38	1.52	.015	0.060			
ECN: S-03946—Rev. D, 09-Jul-01							

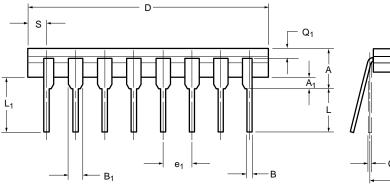
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Document Number: 71261 www.vishay.com 06-Jul-01



#### **CERDIP: 16-LEAD**





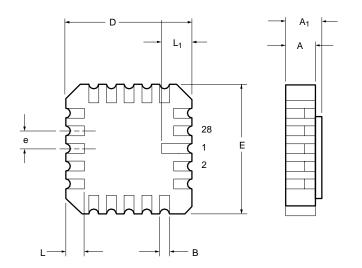
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C	e <sub>A</sub> ~ ~ ~

	MILLIM	IETERS	INC	HES			
Dim	Min	Max	Min	Max			
Α	4.06	5.08	0.160	0.200			
A <sub>1</sub>	0.51	1.14	0.020	0.045			
В	0.38	0.51	0.015	0.020			
B <sub>1</sub>	1.14	1.65	0.045	0.065			
С	0.20	0.30	0.008	0.012			
D	19.05	19.56	0.750	0.770			
E	7.62	8.26	0.300	0.325			
E <sub>1</sub>	6.60	7.62	0.260	0.300			
e <sub>1</sub>	2.54	BSC	0.100	BSC			
e <sub>A</sub>	7.62	BSC	0.300	BSC			
L	3.18	3.81	0.125	0.150			
L <sub>1</sub>	3.81	5.08	0.150	0.200			
$Q_1$	1.27	2.16	0.050	0.085			
S	0.38	1.14	0.015	0.045			
∞	0°	15°	0°	15°			
ECN: S-03946—Rev. G, 09-Jul-01							

Document Number: 71282 www.vishay.com 03-Jul-01 www.vishay.com



### **20-LEAD LCC**



	MILLIM	IETERS	INC	HES				
Dim	Min	Max	Min	Max				
Α	1.37	2.24	0.054	0.088				
A <sub>1</sub>	1.63	2.54	0.064	0.100				
В	0.56	0.71	0.022	0.028				
D	8.69	9.09	0.342	0.358				
E	8.69	9.09	0.442	0.358				
е	1.27	BSC	0.050	BSC				
L	1.14	1.40	0.045	0.055				
L <sub>1</sub>	1.96	2.36	0.077	0.093				
	ECN: S-03946—Rev. B, 09-Jul-01							

DWG: 5321



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Revision: 02-Oct-12 Document Number: 91000

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DG458AK DG459DJ DG459AK DG458DJ-E3 DG458DJ DG459DJ-E3